Power MOSFET 40 V, 0.9 mΩ, 315 A, Single N–Channel

Features

- Small Footprint (5x6 mm) for Compact Design
- Low R_{DS(on)} to Minimize Conduction Losses
- Low Q_G and Capacitance to Minimize Driver Losses
- NTMFS5C410NLTWF Wettable Flank Option for Enhanced Optical Inspection
- These Devices are Pb-Free and are RoHS Compliant

MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Parameter			Symbol	Value	Unit
Drain-to-Source Voltage			V _{DSS}	40	V
Gate-to-Source Voltage			V _{GS}	±20	V
Continuous Drain		$T_C = 25^{\circ}C$	۱ _D	315	А
Current R _{θJC} (Notes 1, 3)	Steady	T _C = 100°C		223	
Power Dissipation	State	$T_{C} = 25^{\circ}C$	PD	167	W
R _{θJC} (Note 1)		$T_{C} = 100^{\circ}C$		83	
Continuous Drain		$T_A = 25^{\circ}C$	۱ _D	48	А
Current R _{θJA} (Notes 1, 2, 3)	Steady State	T _A = 100°C		34	
Power Dissipation		T _A = 25°C	PD	3.8	W
R _{θJA} (Notes 1 & 2)		T _A = 100°C		1.9	
Pulsed Drain Current	T _A = 25	°C, t _p = 10 μs	I _{DM}	900	А
Operating Junction and Storage Temperature			T _J , T _{stg}	–55 to +175	°C
Source Current (Body Diode)			I _S	169	А
Single Pulse Drain-to-Source Avalanche Energy (I _{L(pk)} = 29 A)			E _{AS}	706	mJ
Lead Temperature for Soldering Purposes (1/8" from case for 10 s)			ΤL	260	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL RESISTANCE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
Junction-to-Case - Steady State	$R_{\theta JC}$	0.9	°C/W
Junction-to-Ambient - Steady State (Note 2)	$R_{\theta JA}$	39	

1. The entire application environment impacts the thermal resistance values shown, they are not constants and are only valid for the particular conditions noted.

Surface-mounted on FR4 board using a 650 mm², 2 oz. Cu pad.
Maximum current for pulses as long as 1 second is higher but is dependent

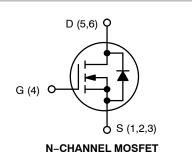
on pulse duration and duty cycle.

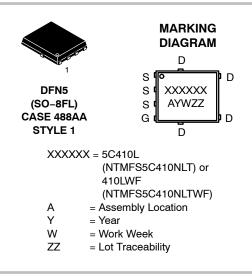


ON Semiconductor®

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V _{(BR)DSS}	R _{DS(ON)} MAX	I _D MAX
40 V	0.9 mΩ @ 10 V	015 4
40 V	1.3 mΩ @ 4.5 V	315 A





ORDERING INFORMATION

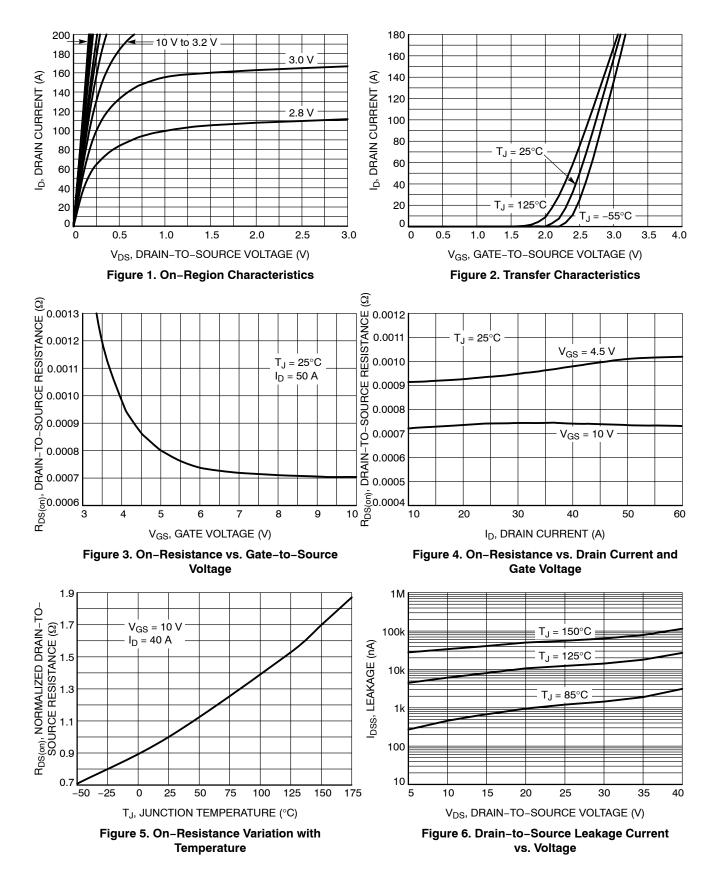
See detailed ordering, marking and shipping information on page 5 of this data sheet.

ELECTRICAL CHARACTERISTICS (T_J = 25°C unless otherwise specified)

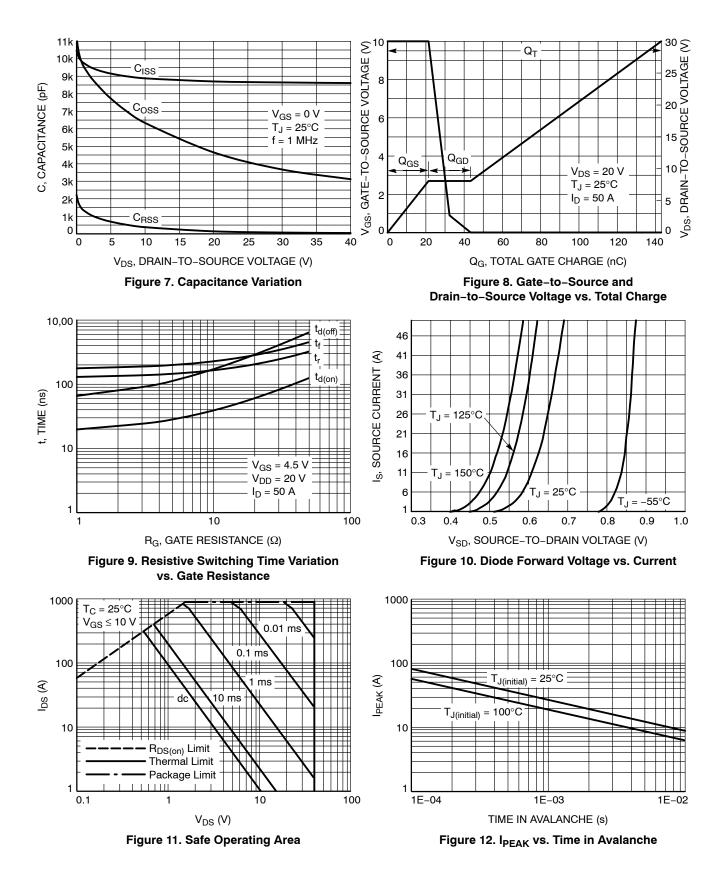
Parameter	Symbol	Test Condition		Min	Тур	Max	Unit
OFF CHARACTERISTICS							
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	V_{GS} = 0 V, I_D = 250 μ A		40			V
Drain-to-Source Breakdown Voltage Temperature Coefficient	V _{(BR)DSS} / T _J				21.2		mV/°C
Zero Gate Voltage Drain Current	I _{DSS}	$V_{GS} = 0 V,$	T _J = 25 °C			10	,
		V _{DS} = 40 V	T _J = 125°C		μA 250	μΑ	
Gate-to-Source Leakage Current	I _{GSS}	$V_{DS} = 0 V, V_{GS} = 20 V$				100	nA
ON CHARACTERISTICS (Note 4)							
Gate Threshold Voltage	V _{GS(TH)}	$V_{GS} = V_{DS}, I_{D}$	= 250 μA	1.2		2.0	V
Threshold Temperature Coefficient	V _{GS(TH)} /T _J				-5.75		mV/°C
Drain-to-Source On Resistance	R _{DS(on)}	V _{GS} = 10 V	I _D = 50 A		0.71	0.9	mΩ
		V_{GS} = 4.5 V	I _D = 50 A		1.0	1.3	
Forward Transconductance	9 FS	V _{DS} = 15 V, I _D = 50 A			190		S
CHARGES, CAPACITANCES & GATE RE	SISTANCE						
Input Capacitance	C _{ISS}			8862		pF	
Output Capacitance	C _{OSS}	V_{GS} = 0 V, f = 1 MHz, V_{DS} = 25 V			4156		
Reverse Transfer Capacitance	C _{RSS}				116		
Total Gate Charge	Q _{G(TOT)}	$V_{GS} = 4.5 \text{ V}, V_{DS} = 20 \text{ V}; \text{ I}_{D} = 50 \text{ A}$ $V_{GS} = 10 \text{ V}, V_{DS} = 20 \text{ V}; \text{ I}_{D} = 50 \text{ A}$ $V_{GS} = 4.5 \text{ V}, V_{DS} = 20 \text{ V}; \text{ I}_{D} = 50 \text{ A}$			66		nC
Total Gate Charge	Q _{G(TOT)}				143		
Threshold Gate Charge	Q _{G(TH)}				6.75		
Gate-to-Source Charge	Q _{GS}				21.4		
Gate-to-Drain Charge	Q _{GD}				22		
Plateau Voltage	V _{GP}				2.7		V
SWITCHING CHARACTERISTICS (Note 5	5)				· · · · · ·		
Turn-On Delay Time	t _{d(ON)}	V_{GS} = 4.5 V, V_{DS} = 20 V, I _D = 50 A, R _G = 1.0 Ω			20		ns
Rise Time	t _r				130		
Turn-Off Delay Time	t _{d(OFF)}				66		
Fall Time	t _f				177		
DRAIN-SOURCE DIODE CHARACTERIS	TICS						4
Forward Diode Voltage	V _{SD}	V _{GS} = 0 V,	$T_J = 25^{\circ}C$		0.73	1.2	2 V
		$I_{\rm S} = 50 \rm A$	T _J = 125°C		0.6		
Reverse Recovery Time	t _{RR}	V _{GS} = 0 V, dIS/dt = 100 A/µs, I _S = 50 A			79.5		ns
Charge Time	ta				39		
Discharge Time	t _b				40.5		
Reverse Recovery Charge	Q _{RR}				126		nC

performance may not be indicated by the Electrical Characteristics if operated under different conditions, t 4. Pulse Test: pulse width $\leq 300 \ \mu$ s, duty cycle $\leq 2\%$. 5. Switching characteristics are independent of operating junction temperatures.

TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS



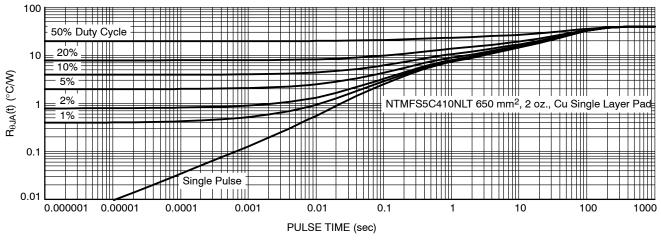


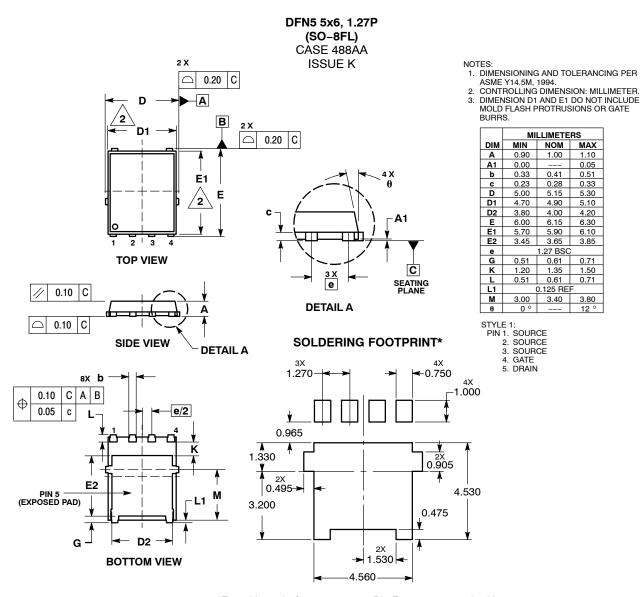
Figure 13. Thermal Characteristics

DEVICE ORDERING INFORMATION

Device	Marking	Package	Shipping [†]
NTMFS5C410NLTT1G	5C410L	DFN5 (Pb-Free)	1500 / Tape & Reel
NTMFS5C410NLTWFT1G	410LWF	DFN5 (Pb-Free, Wettable Flanks)	1500 / Tape & Reel
NTMFS5C410NLTT3G	5C410L	DFN5 (Pb-Free)	5000 / Tape & Reel
NTMFS5C410NLTWFT3G	410LWF	DFN5 (Pb-Free, Wettable Flanks)	5000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PACKAGE DIMENSIONS



*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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